NSN 5961-00-842-9608

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-842-9608 **Inclosure Material:** Metal **Overall Length:** 0.463 inches **Overall Diameter:** 0.375 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 reverse voltage, peak **Current Rating Per Characteristic:** 4.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Terminal q type 1 and 2; junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0